## NSN 5961-01-462-8032

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-462-8032 **Inclosure Material:** Glass **Overall Length:** 0.215 inches **End Application:** 5895-01-417-8475 **Mounting Facility Quantity: Mounting Method: Bracket Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 11.4 regulator voltage, dc and 12.6 regulator voltage, dc **Current Rating Per Characteristic:** 30.60 milliamperes source cutoff current horsepower metric **Power Rating Per Characteristic:** 400.0 milliwatts small-signal input power, common-emitter peak **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air and 65.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 case Shelf Life: N/a **Unit Of Measure: Demilitarization:** 

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